# TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS191C

January 1998 - Revised October 2003

## Features

- Buffered Inputs
- Asynchronous Parallel Load
- Fanout (Over Temperature Range)
  - Standard Outputs ..... 10 LSTTL Loads
- Bus Driver Outputs ..... 15 LSTTL Loads
- Wide Operating Temperature Range .... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types

Pinout

- 4.5V to 5.5V Operation
- Direct LSTTL Input Logic Compatibility, V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
- CMOS Input Compatibility, II  $\leq$  1µA at VOL, VOH

# CD54HC597, CD74HC597, CD74HCT597

# High-Speed CMOS Logic 8-Bit Shift Register with Input Storage

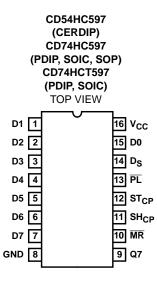
## Description

The 'HC597 and CD74HCT597 are high-speed silicon gate CMOS devices that are pin-compatible with the LSTTL 597 devices. Each device consists of an 8-flip-flop input register and an 8-bit parallel-in/serial-in, serial-out shift register. Each register is controlled by its own clock. A "low" on the parallel load input ( $\overline{PL}$ ) shifts parallel stored data asynchronously into the shift register. A "low" master input ( $\overline{MR}$ ) clears the shift register. Serial input data can also be synchronously shifted through the shift register when  $\overline{PL}$  is high.

### Ordering Information

PART NUMBER	TEMP. RANGE ( <sup>O</sup> C)	PACKAGE
CD54HC597F3A	-55 to 125	16 Ld CERDIP
CD74HC597E	-55 to 125	16 Ld PDIP
CD74HC597M	-55 to 125	16 Ld SOIC
CD74HC597MT	-55 to 125	16 Ld SOIC
CD74HC597M96	-55 to 125	16 Ld SOIC
CD74HC597NSR	-55 to 125	16 Ld SOP
CD74HCT597E	-55 to 125	16 Ld PDIP
CD74HCT597M	-55 to 125	16 Ld SOIC
CD74HCT597MT	-55 to 125	16 Ld SOIC
CD74HCT597M96	-55 to 125	16 Ld SOIC

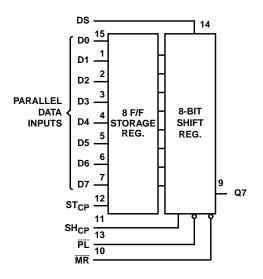
NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.



#### CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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# Functional Diagram



#### FUNCTION TABLE

ST <sub>CP</sub>	SH <sub>CP</sub>	PL	MR	FUNCTION
↑	Х	Х	Х	Data Loaded to Input Flip-Flops
↑	Х	L	Н	Data Loaded from Inputs to Shift Register
No Clock Edge	Х	L	Н	Data Transferred from Input Flip-Flops to Shift Register
Х	Х	L	L	Invalid Logic, State of Shift Register Indeterminate when Signals Removed
Х	х	н	L	Shift Register Cleared
Х	$\uparrow$	Н	Н	Shift Register Clocked Qn = Qn-1, Q0 = $D_S$

H = High Voltage Level, L = Low Voltage Level, X = Don't Care,  $\uparrow$  = Transition from Low to High CP Level

## **Absolute Maximum Ratings**

DC Input Diode Current, $I_{IK}$ For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I <sub>OK</sub>
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Drain Current, per Output, I <sub>O</sub>
For -0.5V < V <sub>O</sub> < V <sub>CC</sub> + 0.5V±25mA
DC Output Source or Sink Current per Output Pin, IO
For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$
DC V <sub>CC</sub> or Ground Current, I <sub>CC</sub> ±50mA

## **Operating Conditions**

Temperature Range, T <sub>A</sub> 55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>
HC Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

#### **Thermal Information**

Thermal Resistance (Typical, Note 1)	θ <sub>JA</sub> ( <sup>o</sup> C/W)
E (PDIP) Package	67
M (SOIC) Package	73
NS (SOP) Package	64
Maximum Junction Temperature	
Maximum Storage Temperature Range	65 <sup>0</sup> C to 150 <sup>0</sup> C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	
M (SOIC) Package NS (SOP) Package Maximum Junction Temperature Maximum Storage Temperature Range	73 64 

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

## **DC Electrical Specifications**

	со		TEST CONDITIONS			25 <sup>0</sup> C		-40 <sup>0</sup> C 1	O 85°C			
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES												
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
	VIL	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output Voltage CMOS Loads	VOH	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μA

#### DC Electrical Specifications (Continued)

		TES CONDI		v <sub>cc</sub>		25 <sup>0</sup> C		-40 <sup>0</sup> C T	O 85°C	-55°C T	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μA
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V <sub>CC</sub> and GND	0	5.5	-		±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

2. For dual-supply systems theoretical worst case (VI = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

## **HCT Input Loading Table**

INPUT	UNIT LOADS
D <sub>S</sub>	0.2
D <sub>n</sub>	0.3
PL, MR	1.5
ST <sub>CP</sub> , SH <sub>CP</sub>	1.5

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications Table, e.g., 360µA max. at 25°C.

### **Prerequisite for Switching Specifications**

			25 <sup>0</sup> C			-40	°C TO 85	5°C	-55 <sup>0</sup>			
PARAMETER	SYMBOL	$V_{CC}(V)$	MIN	ТҮР	MAX	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNITS
HC TYPES											-	
SH <sub>CP</sub> Frequency	f <sub>MAX</sub>	2	6	-	-	5	-	-	4	-	-	MHz
		4.5	30	-	-	25	-	-	20	-	-	MHz
		6	35	-	-	29	-	-	23	-	-	MHz

#### Prerequisite for Switching Specifications (Continued) 25°C -40°C TO 85°C -55°C TO 125°C TYP PARAMETER SYMBOL V<sub>CC</sub>(V) MIN MAX MIN TYP MAX MIN TYP MAX UNITS SHCP Pulse Width tw 2 80 -100 \_ 120 \_ ns 4.5 16 20 24 -\_ ---\_ ns 6 14 20 17 -----ns ST<sub>CP</sub> Pulse Width 2 60 75 90 tw --ns ---4.5 12 15 18 ns ------6 10 13 -15 ns -\_ \_ -MR Pulse Width 2 80 tw -100 --120 ns --4.5 16 20 24 -\_ ---ns 6 14 17 20 -----ns PL Pulse Width 70 2 90 105 --ns tw ---4.5 14 18 21 -ns ----6 12 15 18 ns -----ST<sub>CP</sub> to SH<sub>CP</sub> Setup 2 100 -tsu --125 --150 ns Time 4.5 20 25 30 -----ns 6 17 21 26 ns ------2 50 75 $\mathsf{D}_S$ to $\mathsf{SH}_{CP}$ Setup Time tsu --65 -\_ -ns D<sub>n</sub> to ST<sub>CP</sub> Setup Time 4.5 10 13 15 ns ------6 9 -11 --13 \_ ns -ST<sub>CP</sub> to SH<sub>CP</sub> Setup 2 0 0 0 t<sub>H</sub> -\_ ---\_ ns Time 4.5 0 --0 --0 -ns 6 0 0 0 -ns ---- $\mathsf{D}_S$ to $\mathsf{SH}_{CP}$ Hold Time $\mathsf{D}_n$ to $\mathsf{ST}_{CP}$ Hold Time 2 3 3 3 ns tΗ ------4.5 3 --3 --3 -ns 6 3 3 3 ---\_ -ns 2 3 3 MR to SH<sub>CP</sub> Removal 3 **t**REM -----ns Time 4.5 3 3 3 ---ns --3 3 3 6 --\_ -ns -HCT TYPES SH<sub>CP</sub> Frequency 4.5 25 20 MHz ----16 -fMAX SH<sub>CP</sub> Pulse Width tw 4.5 20 -25 -30 -ns -ST<sub>CP</sub> Pulse Width 4.5 13 16 20 ns tw MR Pulse Width tw 4.5 18 --23 --27 ns **PL** Pulse Width 4.5 tw 16 --20 --24 -ns ST<sub>CP</sub> to SH<sub>CP</sub> Setup 4.5 24 30 36 ----ns tsu -Time

## Prerequisite for Switching Specifications (Continued)

			25 <sup>0</sup> C			-40	°C TO 8	5°C	-55 <sup>0</sup>			
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	ТҮР	MAX	MIN	ТҮР	МАХ	MIN	ТҮР	MAX	UNITS
$D_{S}$ to $SH_{CP}$ Setup Time $D_{n}$ to $ST_{CP}$ Setup Time	tH	4.5	10	-	-	13	-	-	15	-	-	ns
$\mathrm{ST}_{\mathrm{CP}}$ to $\mathrm{SH}_{\mathrm{CP}}$ Hold Time	tн	4.5	0	-	-	0	-	-	0	-	-	ns
$D_{S}$ to $SH_{CP}$ Hold Time $D_{n}$ to $ST_{CP}$ Hold Time	t <sub>H</sub>	4.5	3	-	-	3	-	-	3	-	-	ns
MR to SH <sub>CP</sub> Removal Time	<sup>t</sup> REM	4.5	10	-	-	13	-	-	15	-	-	ns

## Switching Specifications Input tr, tf = 6ns

		TEST			25 <sup>0</sup> C		-40 <sup>0</sup> C 1	o 85 <sup>0</sup> C	-55 <sup>0</sup> C t	o 125 <sup>0</sup> C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	•										
Propagation Delay	tPLH, tPHL	$C_L = 50 pF$	2	-	-	175	-	220	-	265	ns
SH <sub>CP</sub> to Q7			4.5	-	-	35	-	44	-	53	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	30	-	37	-	45	ns
PL to Q7	<sup>t</sup> PLH, <sup>t</sup> PHL	C <sub>L</sub> = 50pF	2	-	-	200	-	250	-	300	ns
			4.5	-	-	40	-	50	-	60	ns
		C <sub>L</sub> =15pF	5	-	17	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	34	-	43	-	51	ns
ST <sub>CP</sub> to Q7	tPLH, tPHL	C <sub>L</sub> = 50pF	2	-	-	240	-	300	-	360	ns
			4.5	-	-	48	-	60	-	72	ns
		C <sub>L</sub> =15pF	5	-	20	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	41	-	51	-	61	ns
MR to Q7	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	Cl	C <sub>L</sub> = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance, (Notes 3, 4)	C <sub>PD</sub>	-	5	-	13.5	-	-	-	-	-	pF
НСТ											
Propagation Delay	t <sub>PLH</sub> , t <sub>PHL</sub>										
SH <sub>CP</sub> to Q7		C <sub>L</sub> = 50pF	4.5	-	-	38	-	48	-	57	ns
		C <sub>L</sub> = 15pF	5	-	16	-	-	-	-	-	ns
PL to Q7	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	48		60		72	ns
		C <sub>L</sub> = 15pF	5	-	20	-	-	-	-	-	ns
ST <sub>CP</sub> to Q7	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	56		70		84	ns
	,	C <sub>L</sub> = 15pF	5	-	23	-	-	-	-	-	ns

		TEST CONDITIONS			25 <sup>0</sup> C		-40°C to 85°C		-55°C to 125°C			
PARAMETER	SYMBOL		$V_{CC}(V)$	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
MR to Q7	t <sub>PLH</sub> , t <sub>PHL</sub>	$C_L = 50 pF$	4.5	-	-	44	-	55	-	66	ns	
		C <sub>L</sub> = 15pF	5	-	18	-	-	-	-	-	ns	
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns	
Input Capacitance	Cl	C <sub>L</sub> = 50pF	-	-	-	10	-	10	-	10	pF	
Power Dissipation Capacitance, (Notes 3, 4)	C <sub>PD</sub>	-	5	-	18.5	-	-	-	-	-	pF	

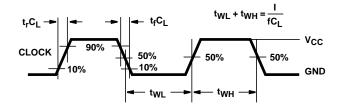
Switching Specifications Input  $t_r$ ,  $t_f = 6ns$  (Continued)

NOTES:

3.  $C_{PD}$  is used to determine the dynamic power consumption, per package.

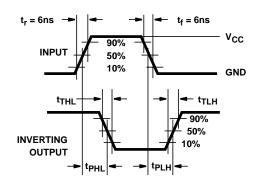
4.  $P_D = C_{PD} V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 f_o)$  where:  $f_i$  = Input Frequency,  $f_o$  = Output Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

## Test Circuits and Waveforms

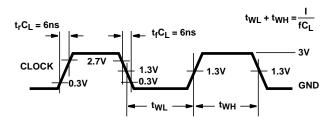


NOTE: Outputs should be switching from 10% V<sub>CC</sub> to 90% V<sub>CC</sub> in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

# FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH







NOTE: Outputs should be switching from 10% V<sub>CC</sub> to 90% V<sub>CC</sub> in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

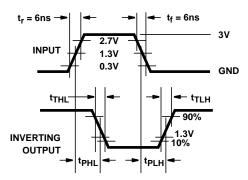
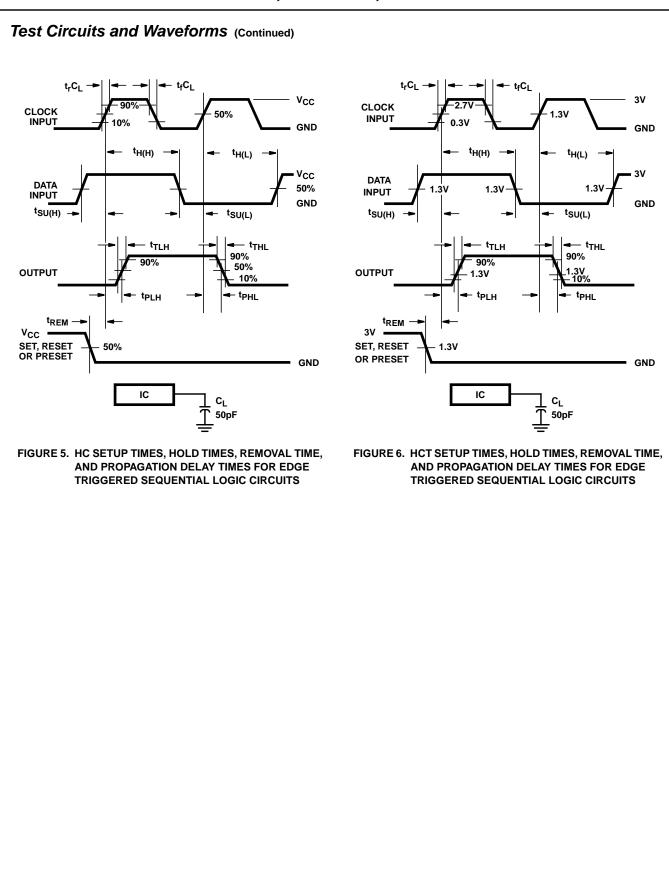
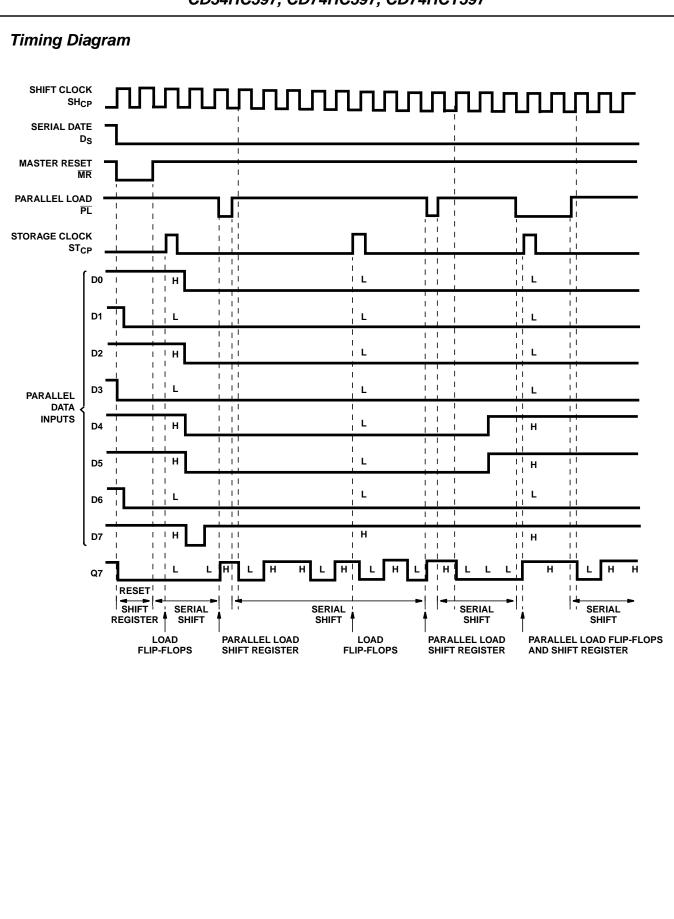


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC







10-Jun-2014

## PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
5962-8681701EA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8681701EA CD54HC597F3A	Samples
CD54HC597F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8681701EA CD54HC597F3A	Samples
CD74HC597E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC597E	Samples
CD74HC597EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC597E	Samples
CD74HC597M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC597M	Samples
CD74HC597M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC597M	Samples
CD74HC597M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC597M	Samples
CD74HC597M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC597M	Samples
CD74HC597MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC597M	Samples
CD74HC597MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC597M	Samples
CD74HC597NSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC597M	Samples
CD74HCT597E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT597E	Samples
CD74HCT597M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	НСТ597М	Samples
CD74HCT597M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	НСТ597М	Samples
CD74HCT597M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	НСТ597М	Samples
CD74HCT597MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	НСТ597М	Samples
CD74HCT597MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT597M	Samples



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10-Jun-2014

(1) The marketing status values are defined as follows:
 ACTIVE: Product device recommended for new designs.
 LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
 NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
 PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
 OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD54HC597, CD74HC597 :

• Catalog: CD74HC597

#### Military: CD54HC597



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PACKAGE OPTION ADDENDUM

10-Jun-2014

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION

#### REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE AND REEL INFORMATION

#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*All dimensions are nomina	I											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC597M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC597NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HCT597M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC597M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC597NSR	SO	NS	16	2000	367.0	367.0	38.0
CD74HCT597M96	SOIC	D	16	2500	333.2	345.9	28.6

J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



4211283-4/E 08/12

# D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## MECHANICAL DATA

## PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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